



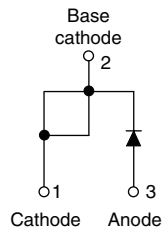
10ETF...PbF Soft Recovery Series

Vishay High Power Products

Fast Soft Recovery Rectifier Diode, 10 A



TO-220AC



FEATURES/DESCRIPTION

The 10ETF...PbF fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

This product series has been designed and qualified for industrial level and lead (Pb)-free.



RoHS*
COMPLIANT

APPLICATIONS

- Output rectification and freewheeling in inverters, choppers and converters
- Input rectifications where severe restrictions on conducted EMI should be met

PRODUCT SUMMARY

V_{RRM}	1000 to 1200 V
V_F at 10 A	< 1.33 V
t_{rr}	80 ns

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNITS
V_{RRM}		1000 to 1200	V
$I_{F(AV)}$	Sinusoidal waveform	10	A
I_{FSM}		160	
t_{rr}	1 A, 100 A/ μ s	80	ns
V_F	10 A, $T_J = 25^\circ\text{C}$	1.33	V
T_J		- 40 to 150	$^\circ\text{C}$

VOLTAGE RATINGS

PART NUMBER	V_{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} AT 150 $^\circ\text{C}$ mA
10ETF10	1000	1100	4
10ETF12	1200	1200	

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	$I_{F(AV)}$	$T_C = 125^\circ\text{C}$, 180 $^\circ$ conduction half sine wave	10	A
Maximum peak one cycle non-repetitive surge current	I_{FSM}	10 ms sine pulse, rated V_{RRM} applied	160	
		10 ms sine pulse, no voltage reapplied	185	
Maximum I^2t for fusing	I^2t	10 ms sine pulse, rated V_{RRM} applied	128	A^2s
		10 ms sine pulse, no voltage reapplied	180	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	$t = 0.1$ to 10 ms, no voltage reapplied	1800	$\text{A}^2\sqrt{\text{s}}$

* Pb containing terminations are not RoHS compliant, exemptions may apply

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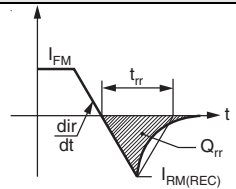
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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V _{FM}	10 A, T _J = 25 °C		1.33	V
Forward slope resistance	r _t	T _J = 150 °C		22.9	mΩ
Threshold voltage	V _{F(TO)}			0.96	V
Maximum reverse leakage current	I _{RM}	T _J = 25 °C	V _R = Rated V _{RRM}	0.1	mA
		T _J = 150 °C		4	

RECOVERY CHARACTERISTICS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Reverse recovery time	t_{rr}	I_F at 10 Apk 25 A/ μs 25 $^{\circ}\text{C}$	310	ns
Reverse recovery current	I_{rr}		4.7	A
Reverse recovery charge	Q_{rr}		1.05	μC
Typical snap factor	S		0.6	



THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J , T _{Stg}		- 40 to 150	°C
Maximum thermal resistance junction to case	R _{thJC}	DC operation	1.5	°C/W
Maximum thermal resistance junction to ambient	R _{thJA}		62	
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.5	
Approximate weight			2	g
			0.07	oz.
Mounting torque	minimum		6 (5)	kgf · cm (lbf · in)
	maximum		12 (10)	
Marking device		Case style TO-220AC (JEDEC)	10ETF12	



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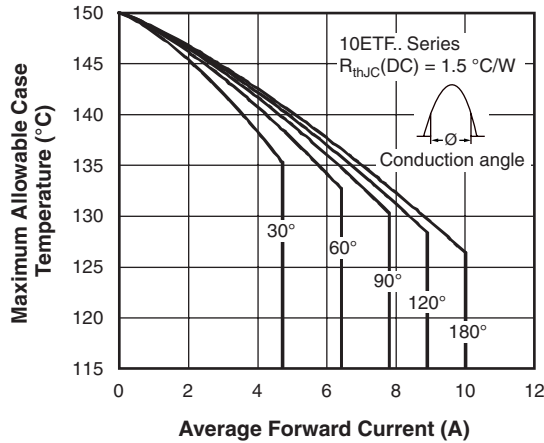


Fig. 1 - Current Rating Characteristics

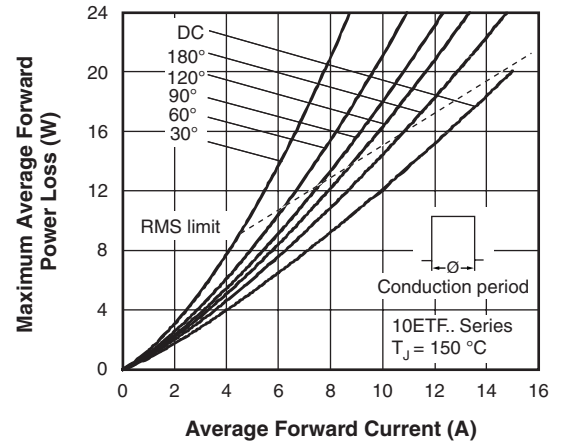


Fig. 4 - Forward Power Loss Characteristics

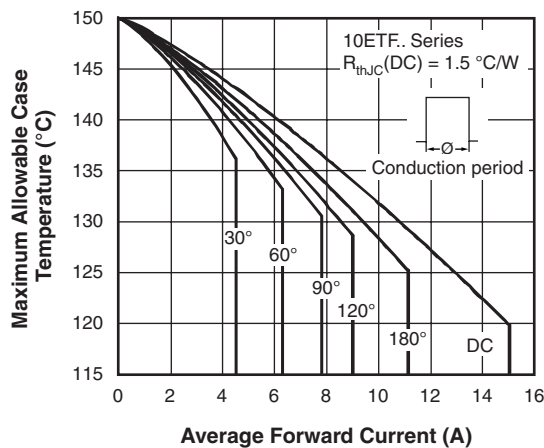


Fig. 2 - Current Rating Characteristics

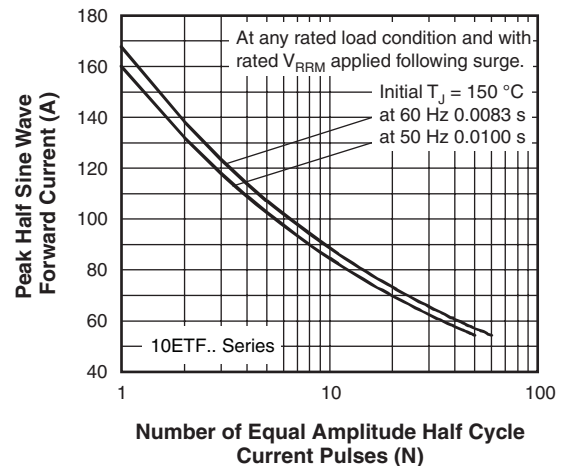


Fig. 5 - Maximum Non-Repetitive Surge Current

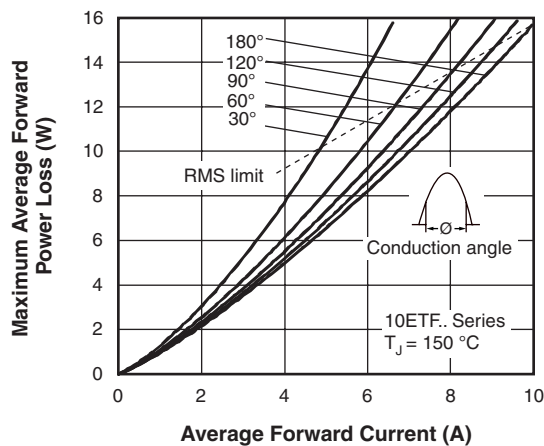


Fig. 3 - Forward Power Loss Characteristics

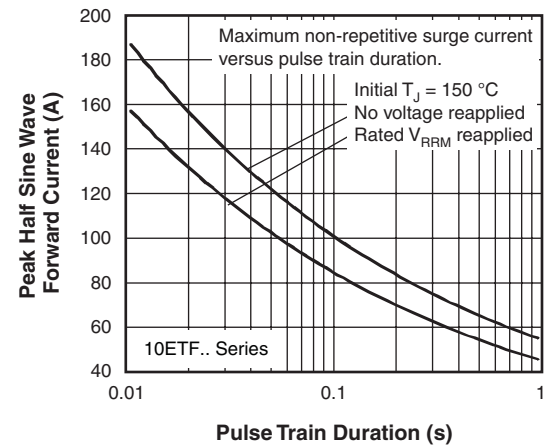


Fig. 6 - Maximum Non-Repetitive Surge Current

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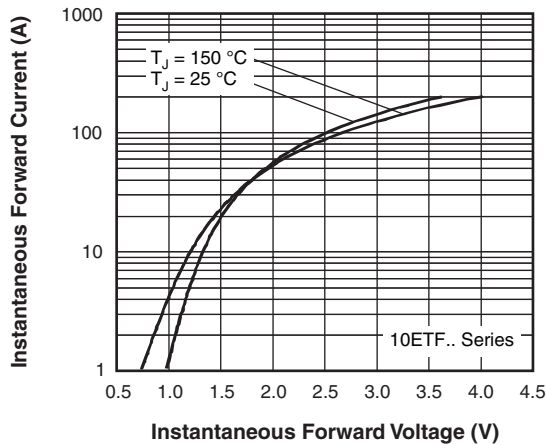


Fig. 7 - Forward Voltage Drop Characteristics

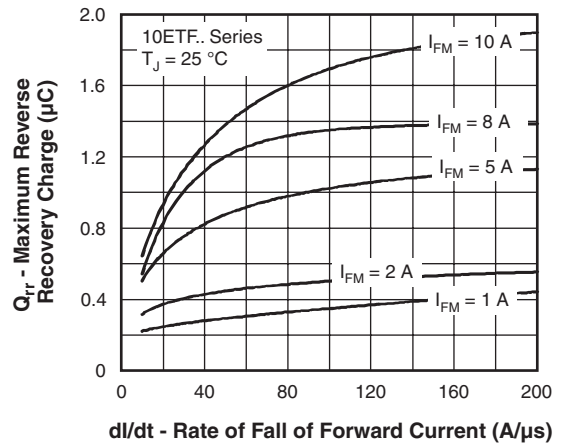


Fig. 10 - Recovery Charge Characteristics, $T_J = 25\text{ }^{\circ}\text{C}$

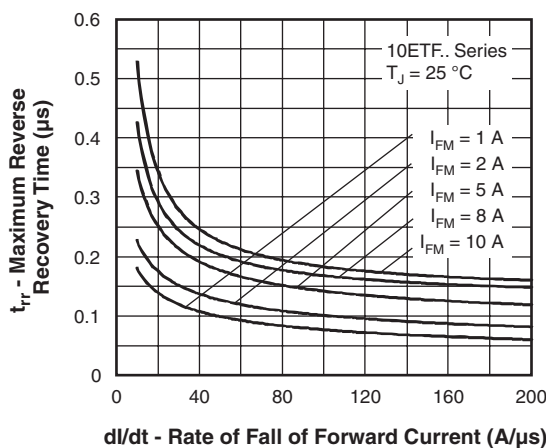


Fig. 8 - Recovery Time Characteristics, $T_J = 25\text{ }^{\circ}\text{C}$

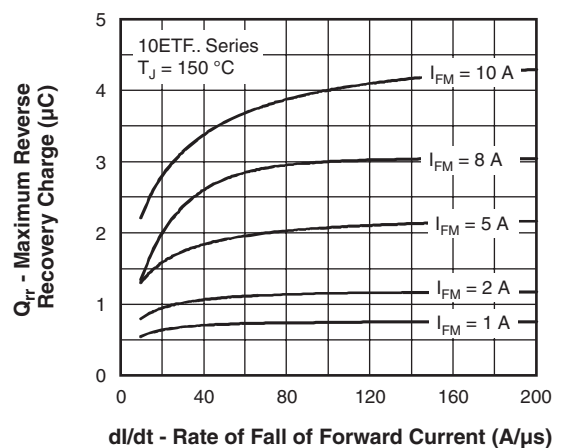


Fig. 11 - Recovery Charge Characteristics, $T_J = 150\text{ }^{\circ}\text{C}$

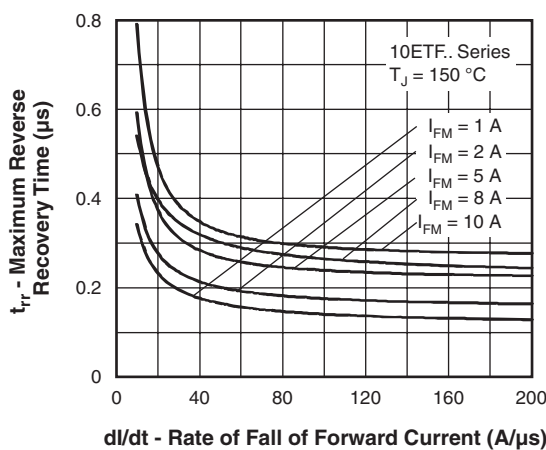


Fig. 9 - Recovery Time Characteristics, $T_J = 150\text{ }^{\circ}\text{C}$

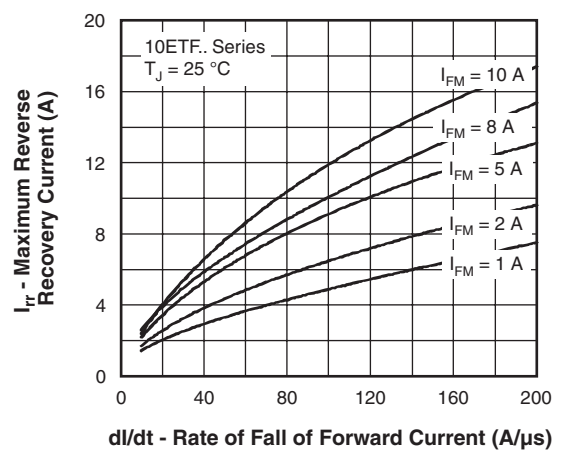


Fig. 12 - Recovery Current Characteristics, $T_J = 25\text{ }^{\circ}\text{C}$



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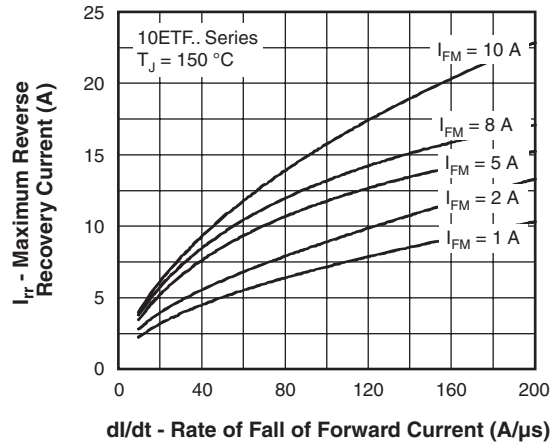


Fig. 13 - Recovery Current Characteristics, $T_J = 150\text{ }^{\circ}\text{C}$

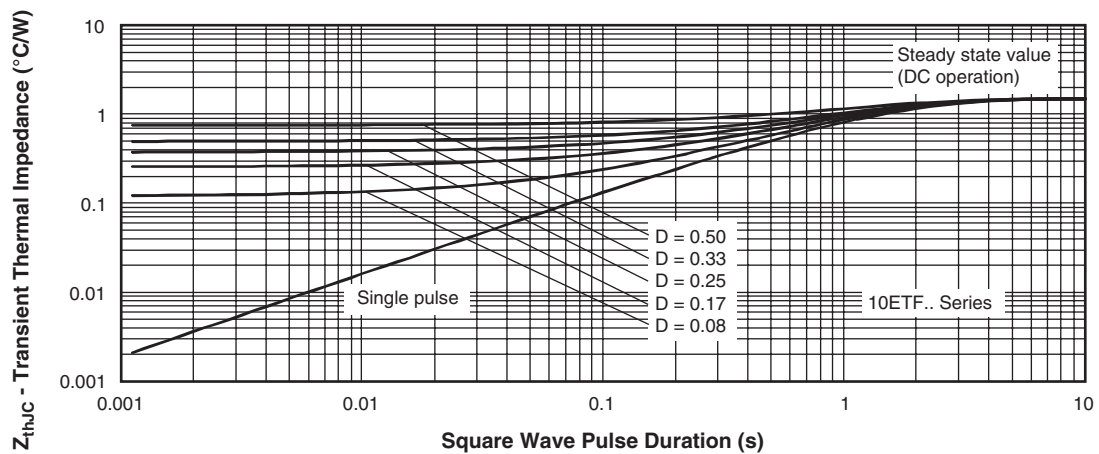


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

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ORDERING INFORMATION TABLE

Device code	10	E	T	F	12	PbF
	1	2	3	4	5	6
	<div><div>1</div><div>-</div><div>Current rating (10 = 10 A)</div></div>					
	<div><div>2</div><div>-</div><div>Circuit configuration: E = Single diode</div></div>					
	<div><div>3</div><div>-</div><div>Package: T = TO-220AC</div></div>					
	<div><div>4</div><div>-</div><div>Type of silicon: F = Fast soft recovery rectifier</div></div>					
	<div><div>5</div><div>-</div><div>Voltage code x 100 = V_{RRM}</div></div>					
	<div><div>6</div><div>-</div><div><div>• None = Standard production</div><div>• PbF = Lead (Pb)-free</div></div></div>					

10 = 1000 V

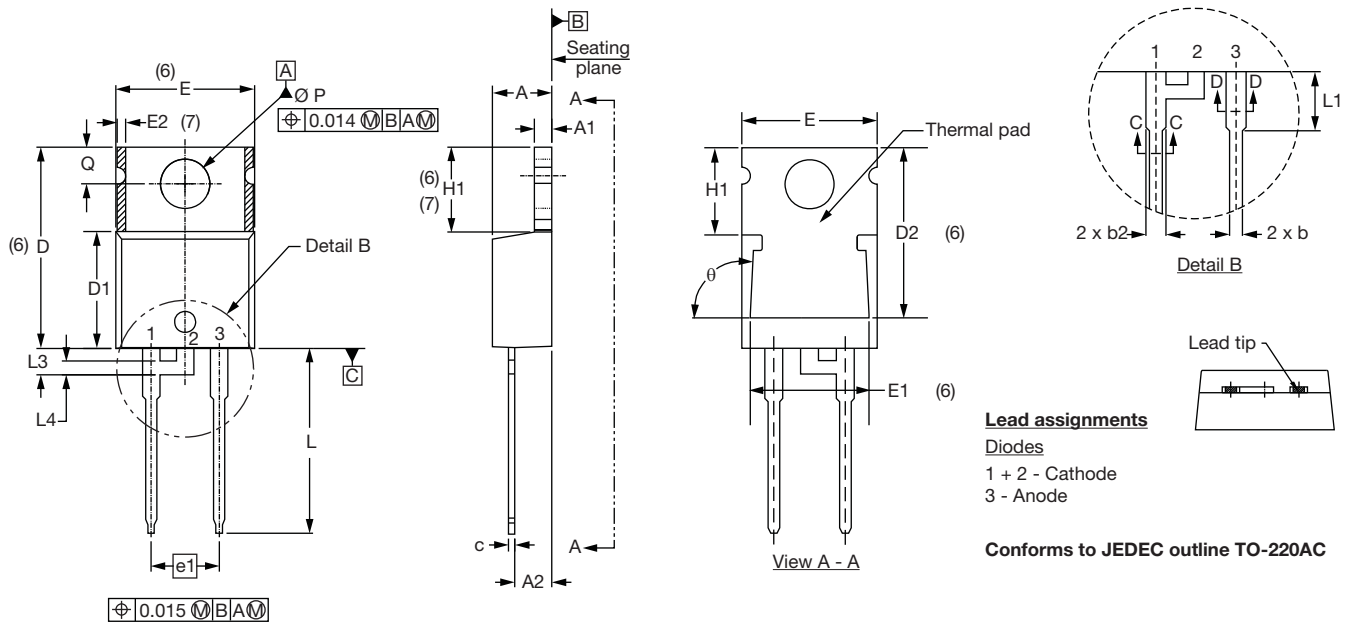
12 = 1200 V

LINKS TO RELATED DOCUMENTS	
Dimensions	http://www.vishay.com/doc?95221
Part marking information	http://www.vishay.com/doc?95224



TO-220AC

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
A	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
c	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6
E	10.11	10.51	0.398	0.414	3, 6

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
e	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
L3	1.78	2.13	0.070	0.084	
L4	0.76	1.27	0.030	0.050	2
Ø P	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° to 93°		90° to 93°		

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline



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